## **Preliminary Data Sheet**





## **Triple Junction TO-9**

High Power Single-Mode and Multi-Mode SemiNex Lasers

- 12xx to 19xx nm
- · Custom Wavelengths Available
- · Lensed Options Available

## Applications

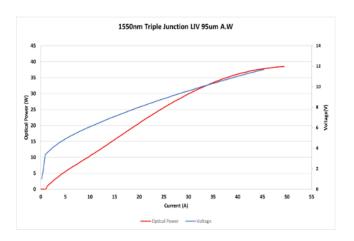
- OEM Medical
- Professional Medical
- LIDAR
- Military / Aerospace
- Illumination

## Features

- Cost effective
   High Output Power
   High Dynamic Range
- High Efficiency
- Standard Low Cost Package
- Fast axis collimated to 5mrad with f=1.2mm lens
- Capped

SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary we will further optimize the design of our InP laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.TO-9 Capped, Fast axis collimated to 5mrad with f=1.2mm lens.







Triple Junction TO9



	Symbol	TO9-265-181	Units
Optical			
Wavelength	λ <sub>c</sub>	1550	nm (±20)
Output Power (<10ns)	P <sub>0</sub>	60.00	watts (±10%)
Output Power (150ns)	P∘	35.00	watts (±10%)
Chip Cavity Length	CL	2500	μm
No. of Junctions		3	
Emitter Width	W	95	μm
Emitter Height	H	10	μm
Spectral Width	δλ	22	nm 3dB
Slope Efficiency	η۰	0.90	W/A
Fast Axis Div.*	⊝_perp	0.3	deg FWHM
Slow Axis Div.	O_parallel	12	deg FWHM
Electrical			
Power Conversion Eff.	η	9	%
Operating Current (<10ns)	I <sub>op</sub>	60	A
Operating Current (150ns)	I <sub>op</sub>	40	A
Threshold Current	I <sub>th</sub>	0.5	A
Operating Voltage	V <sub>op</sub>	11	V
Mechanical			
Weight		1.6	g
Operating Temp.**		-40 to 85	°C
Storage Temp.		-40 to 85	°C

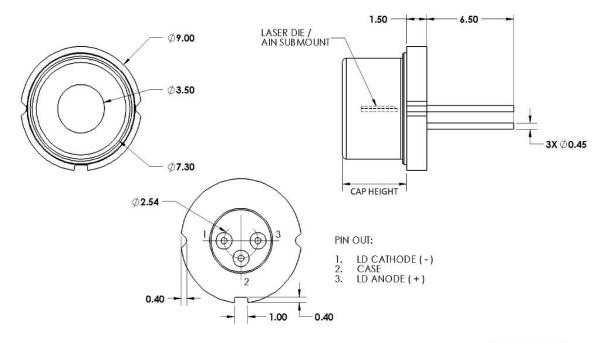
Specified values are rated at a constant heat sink temperature of 20°C.

\*\*Specified operating conditions are based on 20C heat sink temperature. High temperature operation will reduce performance and MTTF.

Unless otherwise indicated all values are nominal.

Uncapped TO9 specifications assume heatsinking underneath Isaer chip.

Capped TO9 specifications assume heatsinking only on flat surface where pins extend.



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